

Y 600mA, 500kHz Micropower Synchronous Boost Converter with Output Disconnect

## **FEATURES**

- Up to 96% Efficiency
- True Output Load Disconnect
- Inrush Current Limiting and Internal Soft-Start
- Low Voltage Start-Up: 0.85V
- Automatic Burst Mode® Operation with I<sub>0</sub> ~ 20µA
- Continuous Switching at Light Loads (LTC3429B)
- Internal Synchronous Rectifier
- Current Mode Control with Internal Compensation
- Short-Circuit Protection
- 500kHz Fixed Frequency Switching
- Input Range: 0.5V to 4.4V
- Output Range: 2.5V to 4.3V (Up to 5V with Schottky)
- Shutdown Current: <1μA</p>
- Antiringing Control Minimizes EMI
- Tiny External Components
- Low Profile (1mm) SOT-23 Package

## **APPLICATIONS**

- MP3 Players
- Digital Cameras
- LCD Bias Supplies
- Handheld Instruments
- Wireless Handsets
- GPS Receivers

## DESCRIPTION

The LTC®3429/LTC3429B are high efficiency synchronous, fixed frequency, step-up DC/DC converters with true output load disconnect, inrush current limiting and soft-start in a low profile 6-lead ThinSOT™ package. These devices are capable of supplying 100mA from a single AA cell input or 250mA from a 2-cell AA with a 3.3V output.

A switching frequency of 500kHz minimizes overall solution footprint by allowing the use of tiny, low profile inductors and ceramic capacitors. Current mode PWM control with internal compensation reduces external parts count thereby saving critical board real estate. The LTC3429 shifts automatically to power saving Burst Mode operation at light loads while the LTC3429B features continuous switching at light loads. Antiringing control circuitry reduces EMI concerns by damping the inductor in discontinuous mode.

The devices also feature low shutdown current of under  $1\mu A$ . The true output disconnect feature allows the output to be completely discharged in shutdown. It also limits the inrush of current during start-up, minimizing surge currents seen by the input supply.

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## TYPICAL APPLICATION

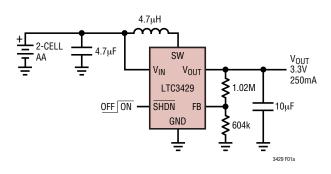
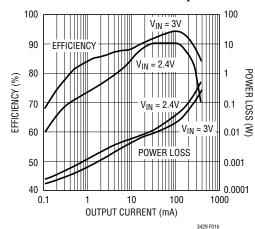


Figure 1. 2-Cell to 3.3V Synchronous Boost Converter

#### 2-Cell to 3.3V Efficiency



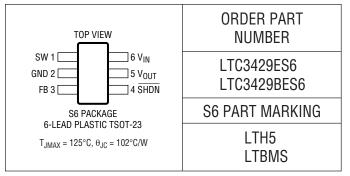


## **ABSOLUTE MAXIMUM RATINGS**

#### (Note 1)

V <sub>IN</sub> Voltage0.3V to 4.	4V
SW Voltage0.3V to	6٧
SHDN, FB Voltage –0.3V to	6V
$V_{OUT}$ $-0.3V$ to	6٧
Operating Temperature Range (Note 2)40°C to 85	o°C
Storage Temperature Range65°C to 15	50°
Lead Temperature (Soldering, 10 sec)300	)°C

## PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

# **ELECTRICAL CHARACTERISTICS** The $\bullet$ denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^{\circ}C$ . $V_{IN} = 1.2V$ , $V_{OUT} = 3.3V$ , unless otherwise specified.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Minimum Start-Up Voltage	I <sub>LOAD</sub> = 1mA, V <sub>OUT</sub> = 0V			0.85	1	V
Minimum Operating Voltage	SHDN = V <sub>IN</sub> (Note 3)			0.5	0.65	V
Output Voltage Adjust Range	(Note 5)		2.5		5	V
Feedback Voltage		•	1.192	1.230	1.268	V
Feedback Input Current	V <sub>FB</sub> = 1.25V			1	50	nA
Quiescent Current (Burst Mode Operation)	V <sub>FB</sub> = 1.4V (Note 4)			20	30	μА
Quiescent Current (Shutdown)	$V_{\overline{SHDN}} = 0V$ , Not Including Switch Leakage, $V_{OUT} = 0V$			0.01	1	μΑ
Quiescent Current (Active)	Measured on V <sub>OUT</sub> , Nonswitching			380	550	μΑ
NMOS Switch Leakage	V <sub>SW</sub> = 5V			0.1	5	μА
PMOS Switch Leakage	$V_{SW} = 5V$ , $V_{OUT} = 0V$			0.1	5	μА
NMOS Switch On Resistance				0.35		Ω
PMOS Switch On Resistance				0.45		Ω
NMOS Current Limit			600	850		mA
Burst Mode Operation Current Threshold	L = 4.7μH (LTC3429 Only)			1.25		mA
Current Limit Delay to Output				40		ns
Max Duty Cycle	V <sub>FB</sub> = 1.15V	•	80	90		%
Switching Frequency		•	380	500	620	kHz
SHDN Input High			1			V
SHDN Input Low					0.35	V
SHDN Input Current	V <sub>SHDN</sub> = 5.5V			0.01	1	μА
Soft-Start Time	▼ SHDN to 90% of V <sub>OUT</sub>			2.5		ms

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** The LTC3429ES6/LTC3429BES6 are guaranteed to meet performance specifications from 0°C to 70°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls.

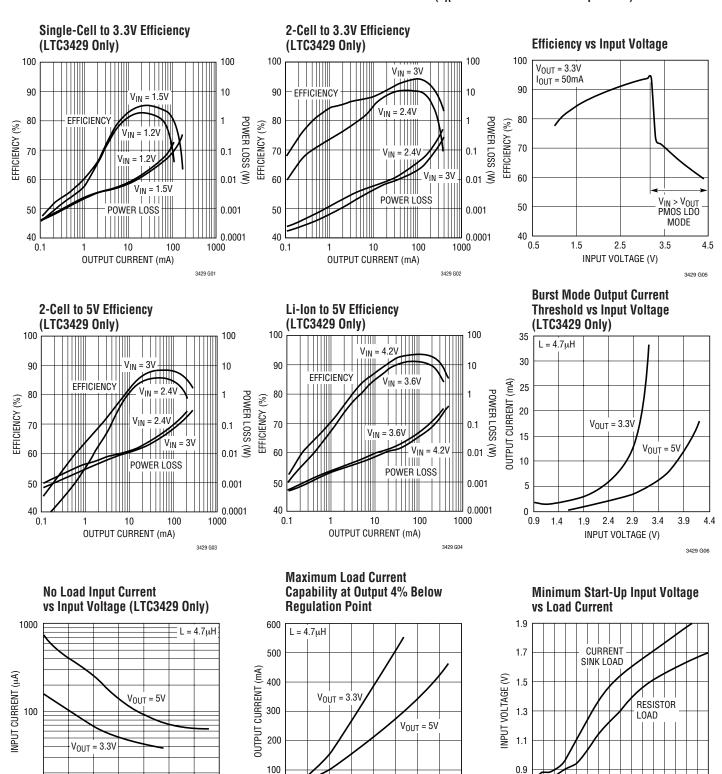
**Note 3:** Minimum  $V_{\text{IN}}$  operation after start-up is only limited by the battery's ability to provide the necessary power as it enters a deeply discharged state.

**Note 4:** Burst Mode operation  $I_Q$  is measured at  $V_{OUT}$ . Multiply this value by  $V_{OUT}/V_{IN}$  to get the equivalent input (battery) current.

**Note 5:** For applications where  $V_{OUT} > 4.3V$ , an external Schottky diode is required. See the Applications Information.

LINEAR

## TYPICAL PERFORMANCE CHARACTERISTICS (TA = 25°C unless otherwise specified)





2.4 2.9

INPUT VOLTAGE (V)

4.4

3429 G07

0.5

2 2.5 3

INPUT VOLTAGE (V)

10

0.9

3429fa

150

100

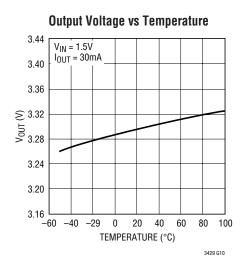
OUTPUT CURRENT (mA)

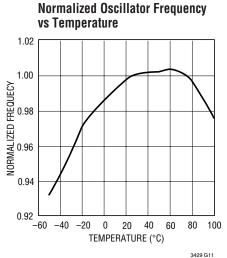
0.7

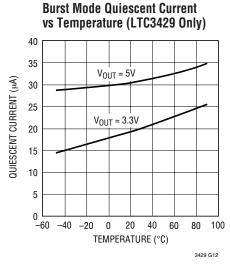
4 4.5

3429 G08

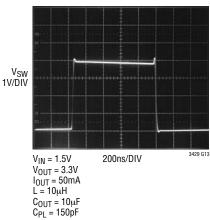
## TYPICAL PERFORMANCE CHARACTERISTICS ( $T_A = 25$ °C unless otherwise specified)



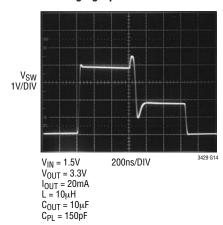




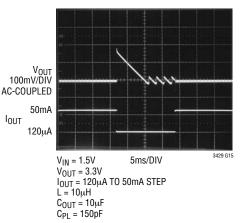
**SW Pin Fixed Frequency Continuous Mode Operation** 



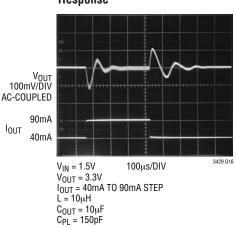
SW Pin Discontinuous Mode **Antiringing Operation** 



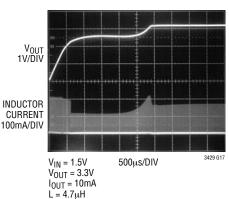
**Fixed Frequency and Burst Mode** Operation (LTC3429 Only)



**Output Voltage Transient** Response



**Inrush Current Control** and Soft-Start

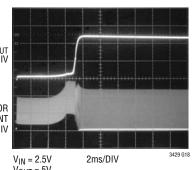


 $C_{OUT}=10\mu F$ 

 $C_{PL} = 100pF$ 

V<sub>OUT</sub> 2V/DIV **INDUCTOR** CURRENT 200mA/DIV

**Inrush Current Control** and Soft-Start



V<sub>OUT</sub> = 5V I<sub>OUT</sub> = 50mA  $L = 4.7 \mu H$  $C_{OUT}=10\mu F$  $C_{PL} = 100pF$ 



## PIN FUNCTIONS

**SW** (Pin 1): Switch Pin. Connect inductor between SW and  $V_{IN}$ . Keep these PCB trace lengths as short and wide as possible to reduce EMI and voltage overshoot. If the inductor current falls to zero, or SHDN is low, an internal  $150\Omega$  antiringing switch is connected from SW to  $V_{IN}$  to minimize EMI.

**GND (Pin 2):** Signal and Power Ground. Provide a short direct PCB path between GND and the (–) side of the output capacitor(s).

**FB** (Pin 3): Feedback Input to the  $g_m$  Error Amplifier. Connect resistor divider tap to this pin. The output voltage can be adjusted from 2.5V to 5V by:

$$V_{OUT} = 1.23V \bullet [1 + (R1/R2)]$$

SHDN (Pin 4): Logic Controlled Shutdown Input.

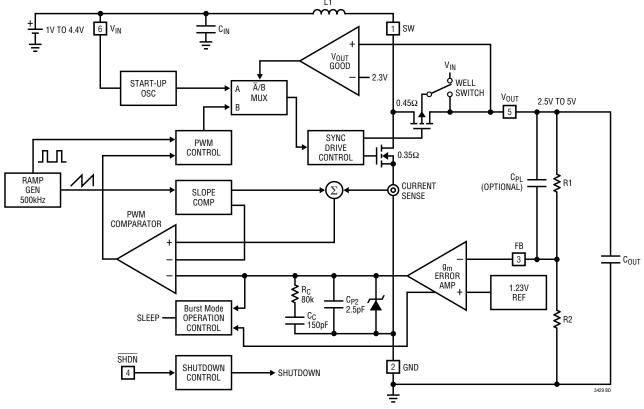
SHDN = High: Normal free running operation, 500kHz typical operating frequency.

SHDN = Low: Shutdown, quiescent current <1 $\mu$ A. Output capacitor can be completely discharged through the load or feedback resistors. A 150 $\Omega$  resistor is internally connected between SW and  $V_{IN}$ .

 $V_{OUT}$  (Pin 5): Output Voltage Sense Input and Drain of the Internal Synchronous Rectifier MOSFET. Bias is derived from  $V_{OUT}$ . PCB trace length from  $V_{OUT}$  to the output filter capacitor(s) should be as short and wide as possible.  $V_{OUT}$  is completely disconnected from  $V_{IN}$  when SHDN is low due to the output disconnect feature.

 $V_{IN}$  (Pin 6): Battery Input Voltage. The device gets its start-up bias from  $V_{IN}$ . Once  $V_{OUT}$  exceeds  $V_{IN}$ , bias comes from  $V_{OUT}$ . Thus, once started, operation is completely independent from  $V_{IN}$ . Operation is only limited by the output power level and the battery's internal series resistance.

## **BLOCK DIAGRAM**





## **OPERATION**

The LTC3429/LTC3429B are 500kHz, synchronous boost converters housed in a 6-lead SOT-23 package. Able to operate from an input voltage below 1V, the device features fixed frequency, current mode PWM control for exceptional line and load regulation. Low  $R_{\text{DS}(\text{ON})}$  internal MOSFET switches enable the device to maintain high efficiency over a wide range of load current. Detailed descriptions of the different operating modes follow. Operation can be best understood by referring to the Block Diagram.

#### **LOW VOLTAGE START-UP**

The LTC3429/LTC3429B include an independent start-up oscillator designed to start up at input voltages of 0.85V typically. The frequency and duty cycle of the start-up oscillator are internally set to 150kHz and 67% respectively. In this mode, the IC operates completely open-loop and the current limit is also set internally to 850mA. Once the output voltage exceeds 2.3V, the start-up circuitry is disabled and normal close-loop PWM operation is initiated. In normal mode, the LTC3429/LTC3429B power themselves from  $V_{OUT}$  instead of  $V_{IN}$ . This allows the battery voltage to drop to as low as 0.5V without affecting the circuit operation. The only limiting factor in the application becomes the ability of the battery to supply sufficient energy to the output. Soft-start and inrush current limiting are provided during start-up as well as normal mode operation.

#### **Soft-Start**

The LTC3429/LTC3429B provide soft-start by charging an internal capacitor with a very weak current source. The voltage on this capacitor, in turn, slowly ramps the peak inductor current from zero to a maximum value of 850mA. The soft-start time is typically 2.5ms, the time it takes to charge the capacitor from zero to 1.35V. However, this time varies greatly with load current, output voltage and input voltage (see Typical Performance Characteristics, Inrush Current Control and Soft-Start). The soft-start capacitor is discharged completely in the event of a commanded shutdown or a thermal shutdown. It is discharged only partially in case of a short circuit at the output.

#### LOW NOISE FIXED FREQUENCY OPERATION

#### Oscillator

The frequency of operation is internally set to 500kHz.

#### **Error Amp**

The error amplifier is an internally compensated transconductance type (current output) with a transconductance  $(g_m) = 33$  microsiemens. The internal 1.23V reference voltage is compared to the voltage at the FB pin to generate an error signal at the output of the error amplifier. A voltage divider from  $V_{OUT}$  to ground programs the output voltage via FB from 2.5V to 5V using the equation:

$$V_{OUT} = 1.23V \cdot [1 + (R1/R2)]$$

#### **Current Sensing**

Lossless current sensing converts the NMOS switch current signal to a voltage to be summed with the internal slope compensation. The summed signal is compared to the error amplifier output to provide a peak current control command for the PWM. Peak switch current is limited to approximately 850mA independent of input or output voltage. The switch current signal is blanked for 60ns to enhance noise rejection.

#### **Zero Current Comparator**

The zero current comparator monitors the inductor current to the output and shuts off the synchronous rectifier once this current reduces to approximately 27mA. This prevents the inductor current from reversing in polarity thereby improving efficiency at light loads.

## **Antiringing Control**

The antiringing control circuitry prevents high frequency ringing of the SW pin as the inductor current goes to zero in discontinuous mode. The damping of the resonant circuit formed by L and  $C_{SW}$  (capacitance on SW pin) is achieved by placing a  $150\Omega$  resistor across the inductor.

#### **Synchronous Rectifier**

To prevent the inductor current from running away, the PMOS synchronous rectifier is only enabled when  $V_{OUT} > (V_{IN} + 0.1V)$  and the FB pin is > 0.8V.



## **OPERATION**

#### Thermal Shutdown

An internal temperature monitor will start to reduce the peak current limit if the die temperature exceeds 125°C. If the die temperature continues to rise and reaches 160°C, the part will go into thermal shutdown, all switches will be turned off and the soft-start capacitor will be reset. The part will be enabled again when the die temperature drops by about 15°C.

#### **Burst Mode OPERATION (LTC3429 Only)**

Portable devices frequently spend extended time in low power or standby mode, only switching to high power consumption when specific functions are enabled. To improve battery life in these types of products, it is important to maintain a high power conversion efficiency over a wide output power range. The LTC3429 provides automatic Burst Mode operation to increase efficiency of the power converter at light loads. Burst Mode operation is initiated if the output load current falls below an internally programmed threshold. This threshold has an inverse dependence on the duty cycle of the converter and also the value of the external inductor (See Typical Performance Characteristics, Output Current Burst Mode Threshold vs V<sub>IN</sub>). Once Burst Mode operation is initiated, only the circuitry required to monitor the output is kept alive and the rest of the device is turned off. This is referred to as the sleep state in which the IC consumes only 20µA from the output capacitor. When the output voltage droops by about 1% from its nominal value, the part wakes up and commences normal PWM operation. The output capacitor recharges and causes the part to re-enter the sleep state if the output load remains less than the Burst Mode threshold. The frequency of this intermittent PWM or burst operation depends on the load current; that is, as the load current drops further below the burst threshold, the LTC3429 turns on less frequently. When the load current increases above the burst threshold, the LTC3429 seamlessly resumes continuous PWM operation. Thus, Burst Mode operation maximizes the efficiency at very light loads by minimizing switching and quiescent losses. However, the output ripple typically increases to about 2% peak-to-peak. Burst Mode ripple can be reduced, in some circumstances, by placing a small phase-lead capacitor  $(C_{Pl})$  between  $V_{OUT}$  and FB pins (refer to the Block Diagram). However, this may adversely affect the efficiency and the quiescent current requirement at light loads. Typical values of C<sub>Pl</sub> range from 15pF to 220pF.

#### **OUTPUT DISCONNECT AND INRUSH LIMITING**

The LTC3429/LTC3429B are designed to allow true output disconnect by eliminating body diode conduction of the internal PMOS rectifier. This allows  $V_{OUT}$  to go to zero volts during shutdown, drawing zero current from the input source. It also allows for inrush current limiting at start-up, minimizing surge currents seen by the input supply. Note that to obtain the advantage of output disconnect, there must not be an external Schottky diode connected between the SWITCH pin and  $V_{OUT}$ .

Board layout is extremely critical to minimize voltage overshoot on the SWITCH pin due to stray inductance. Keep the output filter capacitor as close as possible to the  $V_{OUT}$  pin and use very low ESR/ESL ceramic capacitors tied to a good ground plane. For applications with  $V_{OUT}$  over 4.3V, a Schottky diode is required to limit the peak SWITCH voltage to less than 6V unless some form of external snubbing is employed. This diode must also be placed very close to the pins to minimize stray inductance. See the Applications Information.

#### SHORT CIRCUIT PROTECTION

Unlike most boost converters, the LTC3429/LTC3429B allow their output to be short circuited due to the output disconnect feature. The devices incorporate internal features such as current limit foldback, thermal regulation and thermal shutdown for protection from an excessive overload or short circuit. In the event of a short circuit, the internal soft-start capacitor gets partially discharged. This, in turn, causes the maximum current limit to foldback to a smaller value. In addition to this, a thermal regulation circuit starts to dial back the current limit farther if the die temperature rises above 125°C. If the die temperature still reaches 160°C, the device shuts off entirely.

#### $V_{IN} > V_{OUT}$ OPERATION

The LTC3429/LTC3429B will maintain voltage regulation even if the input voltage is above the output voltage. This



## **OPERATION**

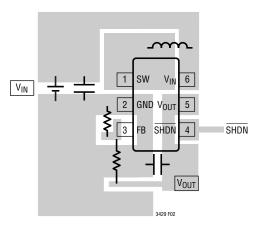
is achieved by terminating the switching of the synchronous PMOS and applying  $V_{\text{IN}}$  statically on its gate. This ensures that the slope of the inductor current will reverse during the time current is flowing to the output. Since the PMOS no longer acts as a low impedance switch in this

mode, there will be more power dissipation within the IC. This will cause a sharp drop in the efficiency (see Typical Performance Characteristics, Efficiency vs  $V_{\text{IN}}$ ). The maximum output current should be limited in order to maintain an acceptable junction temperature.

### APPLICATIONS INFORMATION

#### **PCB LAYOUT GUIDELINES**

The high speed operation of the LTC3429/LTC3429B demands careful attention to board layout. You will not get advertised performance with careless layout. Figure 2 shows the recommended component placement. A large ground pin copper area will help to lower the chip temperature. A multilayer board with a separate ground plane is ideal, but not absolutely necessary.



RECOMMENDED COMPONENT PLACEMENT. TRACES CARRYING HIGH CURRENT ARE DIRECT. TRACE AREA AT FB PIN IS SMALL. LEAD LENGTH TO BATTERY IS SHORT

Figure 2. Recommended Component Placement for Single Layer Board

#### **COMPONENT SELECTION**

#### **Inductor Selection**

The LTC3429/LTC3429B can utilize small surface mount and chip inductors due to its fast 500kHz switching frequency. Typically, a  $4.7\mu$ H inductor is recommended for most applications. Larger values of inductance will allow greater output current capability by reducing the

inductor ripple current. Increasing the inductance above  $10\mu H$  will increase size while providing little improvement in output current capability.

The approximate output current capability of the LTC3429 versus inductance value is given in the equation below and illustrated graphically in Figure 3.

$$I_{OUT(MAX)} = \eta \bullet \left(I_P - \frac{V_{IN} \bullet D}{f \bullet L \bullet 2}\right) \bullet \left(1 - D\right)$$

where:

 $\eta$  = estimated efficiency

 $I_P$  = peak current limit value (0.6A)

V<sub>IN</sub> = input (battery) voltage

D = steady-state duty ratio =  $(V_{OUT} - V_{IN})/V_{OUT}$ 

f = switching frequency (500kHz typical)

L = inductance value

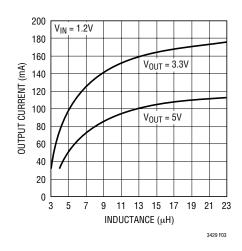


Figure 3. Maximum Output Current vs Inductance Based on 90% Efficiency



## APPLICATIONS INFORMATION

The inductor current ripple is typically set for 20% to 40% of the maximum inductor current (I<sub>P</sub>). High frequency ferrite core inductor materials reduce frequency dependent power losses compared to cheaper powdered iron types, improving efficiency. The inductor should have low ESR (series resistance of the windings) to reduce the I<sup>2</sup>R power losses, and must be able to handle the peak inductor current without saturating. Molded chokes and some chip inductors usually do not have enough core to support the peak inductor currents of 850mA seen on the LTC3429/LTC3429B. To minimize radiated noise, use a toroid, pot core or shielded bobbin inductor. See Table 1 for some suggested components and suppliers.

Table 1. Recommended Inductors

PART	L (µH)	MAX DCR mΩ	HEIGHT (mm)	VENDOR
CDRH5D18-4R1	4.1	57	2.0	Sumida
CDRH5D18-100	10	124	2.0	www.sumida.com
CDRH3D16-4R7	4.7	105	1.8	
CDRH3D16-6R8		170	1.8	
CR43-4R7	4.7	109	3.5	
CR43-100	10	182	3.5	
CMD4D06-4R7MC	4.7	216	0.8	
CMD4D06-3R3MC	3.3	174	0.8	
DS1608-472	4.7	60	2.9	Coilcraft
DS1608-103	10	75	2.9	www.coilcraft.com
D01608C-472	4.7	90	2.9	
D52LC-4R7M	4.7	84	2.0	Toko
D52LC-100M	10	137	2.0	www.tokoam.com
LQH32CN4R7M24	4.7	195	2.2	Murata www.murata.com

#### **Output and Input Capacitor Selection**

Low ESR (equivalent series resistance) capacitors should be used to minimize the output voltage ripple. Multilayer ceramic capacitors are an excellent choice as they have extremely low ESR and are available in small footprints. A  $4.7\mu F$  to  $15\mu F$  output capacitor is sufficient for most applications. Larger values up to  $22\mu F$  may be used to obtain extremely low output voltage ripple and improve transient response. An additional phase lead capacitor may be required with output capacitors larger than  $10\mu F$  to maintain acceptable phase margin. X5R and X7R dielectric materials are preferred for their ability to maintain capacitance over wide voltage and temperature ranges.

Low ESR input capacitors reduce input switching noise and reduce the peak current drawn from the battery. It follows that ceramic capacitors are also a good choice for input decoupling and should be located as close as possible to the device. A  $10\mu F$  input capacitor is sufficient for virtually any application. Larger values may be used without limitations. Table 2 shows a list of several ceramic capacitor manufacturers. Consult the manufacturers directly for detailed information on their entire selection of ceramic capacitors.

**Table 2. Capacitor Vendor Information** 

SUPPLIER	WEBSITE
AVX	www.avxcorp.com
Murata	www.murata.com
Taiyo Yuden	www.t-yuden.com

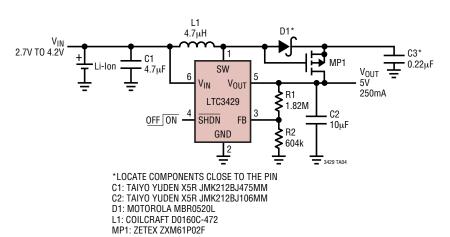
## TYPICAL APPLICATIONS

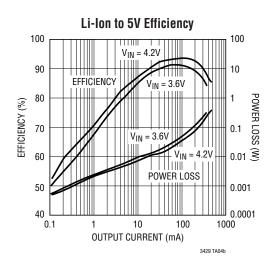
### Applications Where $V_{OUT} > 4.3V$

When the output voltage is programmed above 4.3V, it is necessary to add a Schottky diode either from SW to  $V_{OUT}$ , or to add a snubber network in order to maintain an acceptable peak voltage on the SW pin. The Schottky diode between SW and  $V_{OUT}$  will provide a peak efficiency

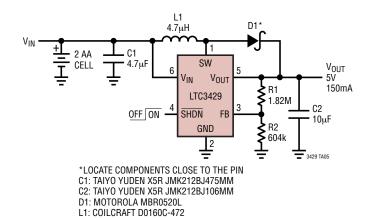
improvement but will negate the output disconnect feature. If output disconnect is required, an active snubber network is suggested as shown below. Examples of Schottky diodes are: MBR0520L, PMEG2010EA, 1N5817 or equivalent.

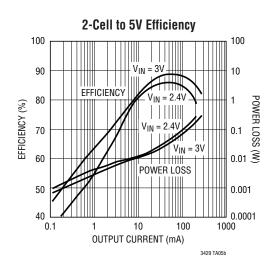
#### Application Circuit for V<sub>OUT</sub> > 4.3V Where Inrush Current Limiting and Output Disconnect are Required





#### Application Circuit for $V_{OUT} > 4.3V$ Where Inrush Current Limiting and Output Disconnect are Not Required



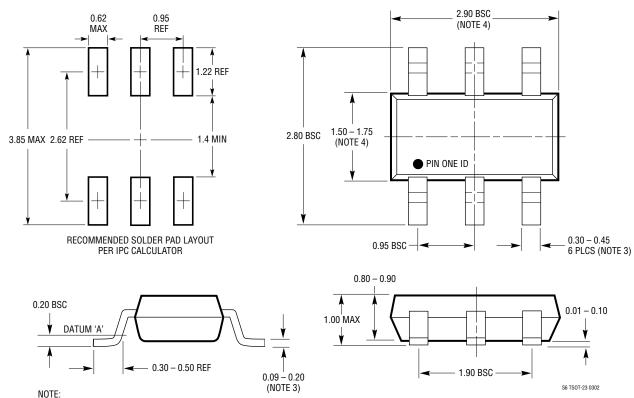


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## PACKAGE DESCRIPTION

#### S6 Package 6-Lead Plastic TSOT-23

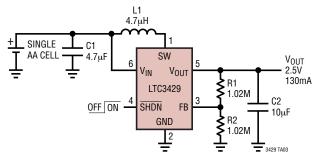
(Reference LTC DWG # 05-08-1636)



- 1. DIMENSIONS ARE IN MILLIMETERS
  2. DRAWING NOT TO SCALE
- 3. DIMENSIONS ARE INCLUSIVE OF PLATING
- 4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
- 5. MOLD FLASH SHALL NOT EXCEED 0.254mm
- 6. JEDEC PACKAGE REFERENCE IS MO-193

## TYPICAL APPLICATION

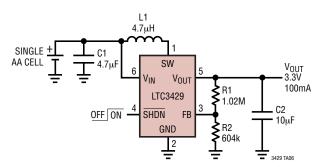
Single AA Cell to 2.5V Synchronous Boost Converter



C1: TAIYO YUDEN X5R JMK212BJ475MM C2: TAIYO YUDEN X5R JMK212BJ106MM

L1: COILCRAFT D0160C-472

#### Single AA Cell to 3.3V



C1: TAIYO YUDEN X5R JMK212BJ475MM C2: TAIYO YUDEN X5R JMK212BJ106MM

L1: COILCRAFT D0160C-472

## RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1613	550mA (I <sub>SW</sub> ), 1.4MHz High Efficiency Step-Up DC/DC Converter	90% Efficiency, V <sub>IN</sub> : 0.9V to 10V, V <sub>OUT(MAX)</sub> = 34V, I <sub>Q</sub> = 3mA, I <sub>SD</sub> < 1 $\mu$ A, ThinSOT
LT1615/LT1615-1	300mA/80mA (I <sub>SW</sub> ), High Efficiency Step-Up DC/DC Converters	$V_{IN}\!\!:$ 1V to 15V, $V_{OUT(MAX)}=34V,$ $I_Q=20\mu A,$ $I_{SD}<1\mu A,$ ThinSOT
LT1618	1.5A (I <sub>SW</sub> ), 1.25MHz High Efficiency Step-Up DC/DC Converter	90% Efficiency, V <sub>IN</sub> : 1.6V to 18V, V <sub>OUT(MAX)</sub> = 35V, I <sub>Q</sub> = 1.8mA, I <sub>SD</sub> < 1 $\mu$ A
LTC1700	No R <sub>SENSE</sub> ™, 530kHz, Synchronous Step-Up DC/DC Controller	95% Efficiency, $V_{IN}$ : 0.9V to 5V, $I_Q$ = 200 $\mu$ A, $I_{SD}$ < 10 $\mu$ A, MS10
LT1930/LT1930A	1A (I <sub>SW</sub> ), 1.2MHz/2.2MHz, High Efficiency Step-Up DC/DC Converters	High Efficiency, $V_{IN}$ : 2.6V to 16V, $V_{OUT(MAX)}$ = 34V, $I_Q$ = 4.2mA/5.5mA, $I_{SD}$ < 1 $\mu$ A, ThinSOT
LT1946/LT1946A	1.5A (I <sub>SW</sub> ), 1.2MHz/2.7MHz, High Efficiency Step-Up DC/DC Converters	High Efficiency, $V_{IN}$ : 2.45V to 16V, $V_{OUT(MAX)}$ = 34V, $I_Q$ = 32mA, $I_{SD}$ < 1 $\mu$ A, MS8
LT1961	1.5A (I <sub>SW</sub> ), 1.25MHz High Efficiency Step-Up DC/DC Converter	90% Efficiency, V <sub>IN</sub> : 3V to 25V, V <sub>OUT(MAX)</sub> = 35V, I <sub>Q</sub> = 0.9mA, I <sub>SD</sub> < $6\mu A$ , MS8E
LTC3400/LTC3400B	600mA (I <sub>SW</sub> ), 1.2MHz, Synchronous Step-Up DC/DC Converters	92% Efficiency, $V_{IN}$ : 0.85V to 5V, $V_{OUT(MAX)}$ = 5V, $I_Q$ = 19 $\mu$ A/300 $\mu$ A, $I_{SD}$ < 1 $\mu$ A, ThinSOT
LTC3401/LTC3402	1A/2A (I <sub>SW</sub> ), 3MHz, Synchronous Step-Up DC/DC Converters	97% Efficiency, V <sub>IN</sub> : 0.5V to 5V, V <sub>OUT(MAX)</sub> = 5.5V, I <sub>Q</sub> = 38 $\mu$ A, I <sub>SD</sub> < 1 $\mu$ A, MS10
LTC3421	3A (I <sub>SW</sub> ), 3MHz, Synchronous Step-Up DC/DC Converter with Output Disconnect	95% Efficiency, $V_{IN}$ : 0.5V to 4.5V, $V_{OUT(MAX)}$ = 5.25V, $I_Q$ = 12 $\mu$ A, $I_{SD}$ < 1 $\mu$ A, QFN24
LTC3425	5A (I <sub>SW</sub> ), 8MHz, 4-Phase Synchronous Step-Up DC/DC Converter with Output Disconnect	95% Efficiency, V <sub>IN</sub> : 0.5V to 4.5V, V <sub>OUT(MAX)</sub> = 5.25V, I <sub>Q</sub> = 12 $\mu$ A, I <sub>SD</sub> < 1 $\mu$ A, QFN32
LT3464	85mA (I <sub>SW</sub> ), High Efficiency Step-Up DC/DC Converter with Integrated Schottky and PNP Disconnect	$V_{IN}\!\!: 2.3V$ to 10V, $V_{OUT(MAX)}\!= 34V,$ $I_Q = 25\mu A,$ $I_{SD} < 1\mu A,$ ThinSOT

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